



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

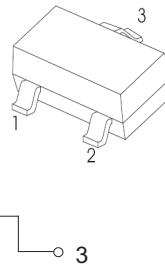
## SOT-23 Plastic-Encapsulate Diodes

**RB491D** Schottky Barrier Diode

### FEATURES

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

**SOT-23**



Marking: D2E

### Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	Limit	Unit
Peak reverse voltage	V <sub>RM</sub>	25	V
DC reverse voltage	V <sub>R</sub>	20	V
Mean rectifying current	I <sub>F</sub>	1	A
Peak forward surge current	I <sub>FSM</sub>	3	A
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55~+150	°C

### Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V <sub>F</sub>			0.45	V	I <sub>F</sub> =1A
Reverse current	I <sub>R</sub>			200	μA	V <sub>R</sub> =20V